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PATENT
Attorney Docket No.: SAM-0234

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Sung-bae Park, *et al.*

Examiner: Lewis, M.

Serial No.: 09/924,787

Group Art Unit: 2822

Filed: August 8, 2001

Title: SOI MOSFET HAVING BODY CONTACT FOR PREVENTING FLOATING
BODY EFFECT AND METHOD OF FABRICATING THE SAME

CERTIFICATE OF MAILING UNDER 37 C.F.R. § 1.8

I hereby certify that this correspondence is being deposited with the United States Post Office as First Class Mail on the date indicated below in an envelope addressed to BOX NON-FEE AMENDMENT, Assistant Commissioner for Patents, Washington, DC 20231.

August 21, 2002
Date

Lisa Sanders
Lisa Sanders

BOX NON-FEE AMENDMENT

Assistant Commissioner for Patents
Washington, D.C. 20231

AMENDMENT A

Sir:

This is in response to the Office Action mailed on May 22, 2002.

Please amend the application as follows:

In the Claims

Please amend the claims as follows:

1. (Amended) A silicon-on-insulator metal oxide semiconductor field effect transistor (SOI MOSFET) comprising:

- a semiconductor substrate;
- a buried oxide layer formed on the semiconductor substrate;
- a body on the buried oxide layer, the body being an active region of a transistor;
- a gate oxide layer formed on the body;
- a gate formed on the gate oxide layer;

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